



RELIABILITY REPORT
FOR
MAX2204EXK+T
PLASTIC ENCAPSULATED DEVICES

December 7, 2010

MAXIM INTEGRATED PRODUCTS

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Conclusion

The MAX2204EXK+T successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX2204 RF power detector is designed to operate from 450MHz to 2.5GHz. The device is ideal for wideband code-division multiple access (WCDMA), cdma2000®, and high-speed downlink/uplink packet access. The MAX2204 accepts an RF signal at the input, and outputs a highly repeatable voltage. The output voltage increases monotonically with increasing input power. The device is designed to compensate for temperature and process shifts, reducing the typical output variation to less than $\pm 0.5\text{dB}$ at full input power and $\pm 1.5\text{dB}$ at the lower power. The MAX2204 features a detection range from -16dBm to $+5\text{dBm}$. High input impedance allows for low-loss resistive tap if an isolator is used. The device uses external termination at the input so that the RF signal from several directional couplers can be connected to a single detector chip. The MAX2204 operates from a 2.7V to 3.3V power supply. The device is available in a tiny 5-pin SC70 package. Electrical performance is guaranteed over a -40°C to $+85^\circ\text{C}$ temperature range.

II. Manufacturing Information

A. Description/Function:	RF Power Detector
B. Process:	GST2
C. Number of Device Transistors:	
D. Fabrication Location:	Oregon
E. Assembly Location:	Malaysia and Thailand
F. Date of Initial Production:	April 20, 2007

III. Packaging Information

A. Package Type:	5-pin SC70
B. Lead Frame:	Alloy42
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-2683
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	324°C/W
K. Single Layer Theta Jc:	115°C/W
L. Multi Layer Theta Ja:	324°C/W
M. Multi Layer Theta Jc:	115°C/W

IV. Die Information

A. Dimensions:	30 X 31 mils
B. Passivation:	Si ₃ N ₄ (Silicon nitride)
C. Interconnect:	Au
D. Backside Metallization:	None
E. Minimum Metal Width:	2 microns (as drawn)
F. Minimum Metal Spacing:	2 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts:	Richard Aburano (Manager, Reliability Operations) Bryan Preeshl (Vice President of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet. 0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 150°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 50 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 22.0 \times 10^{-9}$$
$$\lambda = 22.0 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maxim-ic.com/qa/reliability/monitor>. Cumulative monitor data for the GST2 Process results in a FIT Rate of 0.06 @ 25C and 1.10 @ 55C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing (lot NECZCU003A, D/C 0807)

The WC25 die type has been found to have all pins able to withstand a HBM transient pulse of +/- 2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/- 250mA and overvoltage per JEDEC JESD78.

Table 1
Reliability Evaluation Test Results

MAX2204EXK+T

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (Note 1)	Ta = 150°C Biased Time = 192 hrs.	DC Parameters & functionality	50	0	NECZBQ001B, D/C 0708

Note 1: Life Test Data may represent plastic DIP qualification lots.